



SS32B THRU SS320B

VOLTAGE RANGE	20 to 200 Volts
CURRENT	3.0 Ampere

Features



- The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- For surface mounted applications
- Metal silicon junction, majority carrier conduction
- Low power loss, high efficiency
- Built-in strain relief, ideal for automated placement
- High forward surge current capability
- High temperature soldering guaranteed: 260 C/10 seconds at terminals



DO-214AA (SMB J-Bend)

Mechanical Data

- Case: Transfer molded plastic
- Epoxy: UL 94V-0 rate flame retardant
- Lead :Solder plated, solderable per MIL-STD-750 method 2026
- Polarity: Color band denotes cathode end
- Weight: 0.003ounce, 0.093 gram

Maximum Ratings and Electrical Characteristics

- Ratings at 25°C ambient temperature unless otherwise specified
- Single phase, half wave, 60Hz, resistive or inductive load
- For capacitive load derate current by 20%

TYPE NUMBER	SYMBOL	SS 32B	SS 34B	SS 35B	SS 36B	SS 38B	SS 310B	SS 315B	SS 320B	UNIT
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	20	40	50	60	80	100	150	200	Volts
Maximum RMS Voltage	V_{RMS}	14	28	35	42	56	70	105	140	Volts
Maximum DC Blocking Voltage	V_{DC}	20	40	50	60	80	100	150	200	Volts
Maximum Average Forward Rectified Current at T_L see figure 1 $T_L = 100^\circ\text{C}$	$I_{(AV)}$	3.0								Amps
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	I_{FSM}	80								Amps
Maximum Instantaneous Forward Voltage @ 3.0A(Note1)	V_F	0.55	0.70		0.85		0.90		Volts	
Maximum DC Reverse Current at rated DC Blocking Voltage per element	$T_A = 25^\circ\text{C}$	0.1						0.01		mA
	$T_A = 100^\circ\text{C}$	20.0				10.0		2.0		
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	50								$^\circ\text{C/W}$
	$R_{\theta JL}$	12								
Diode junction capacitance (Note 3)	C_J	300			200					pF
Operating Junction Temperature	T_J	(-55 to +150)						(-65 to +175)		$^\circ\text{C}$
Storage Temperature Range	T_{STG}	(-55 to +150)								$^\circ\text{C}$

Notes:

1. Pulse test: 300 μs pulse width, 1% duty cycle.
2. Thermal resistance from Junction to ambient and from junction to lead mounted on PCB. with 0.3 \times 0.3"(8.0 \times 8.0mm)copper pad areas.
3. f=1MHz and applied 4V DC reverse voltage.



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Ratings and Characteristic Curves (TA=25°C unless otherwise noted)

FIG.1-FORWARD CURRENT DERATING CURVE

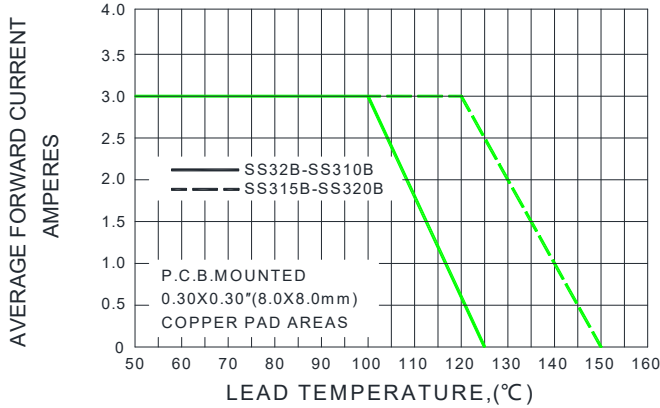


FIG.2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

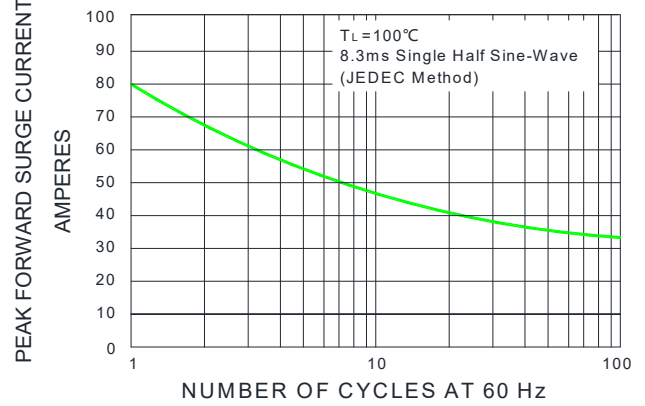


FIG.3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

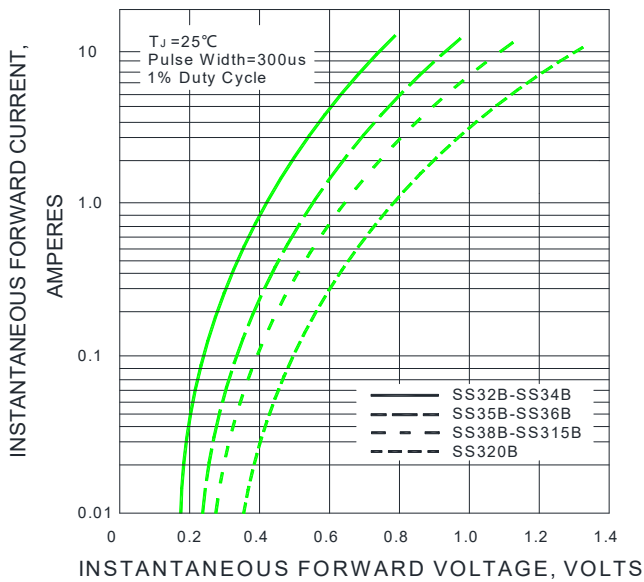


FIG.4-TYPICAL REVERSE CHARACTERISTICS

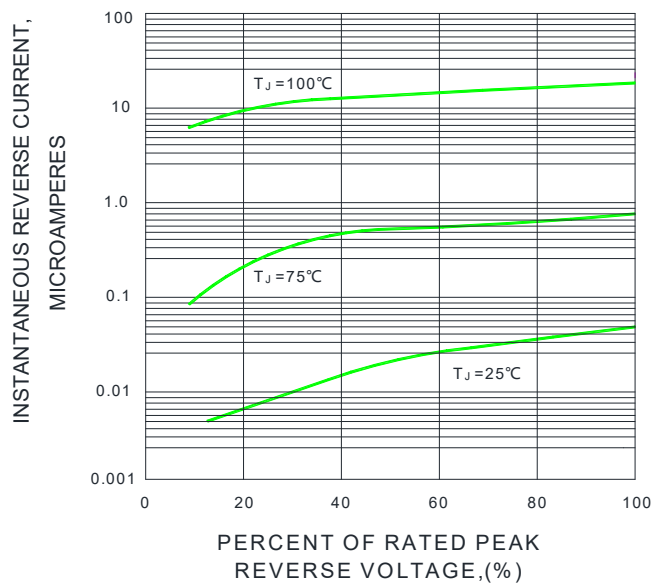
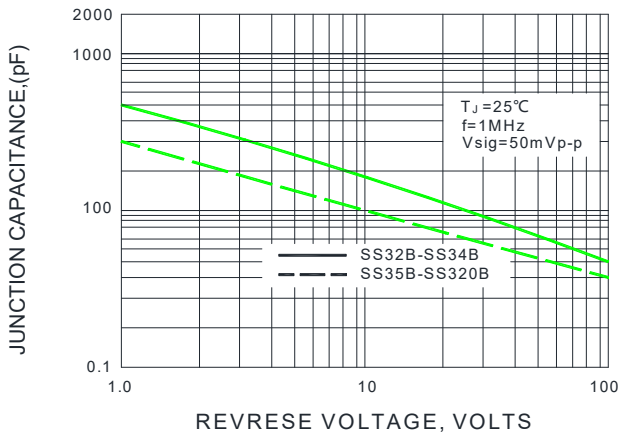


FIG.5-TYPICAL JUNCTION CAPACITANCE

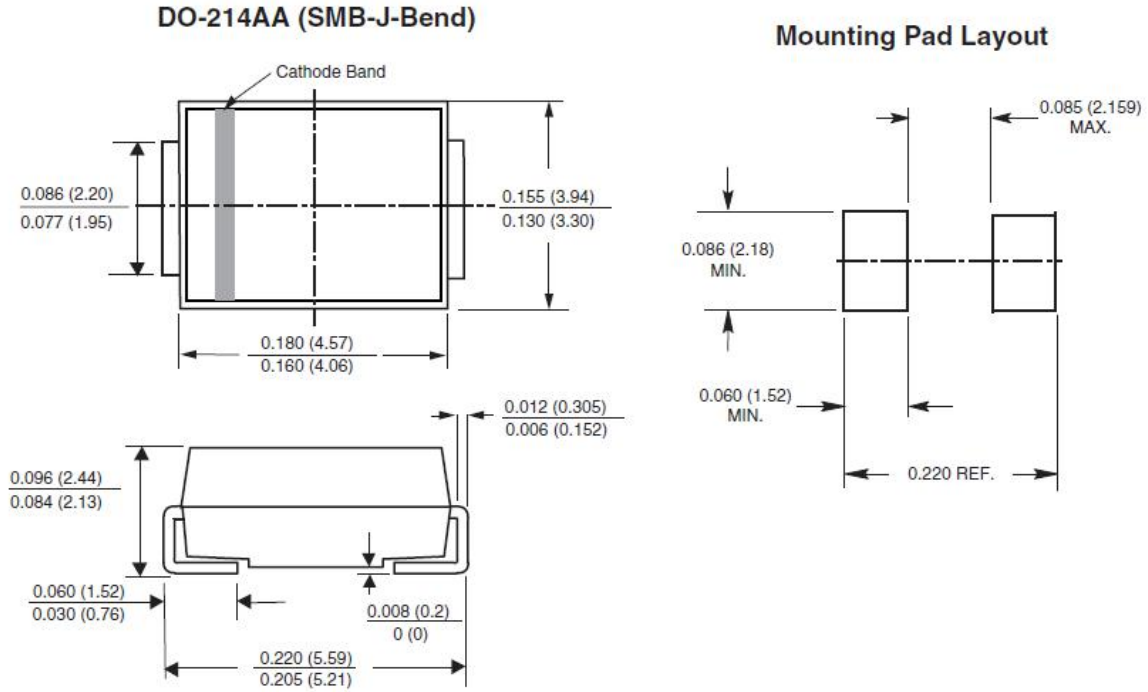




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Package Outline Dimensions in inches (millimeters)



Marking

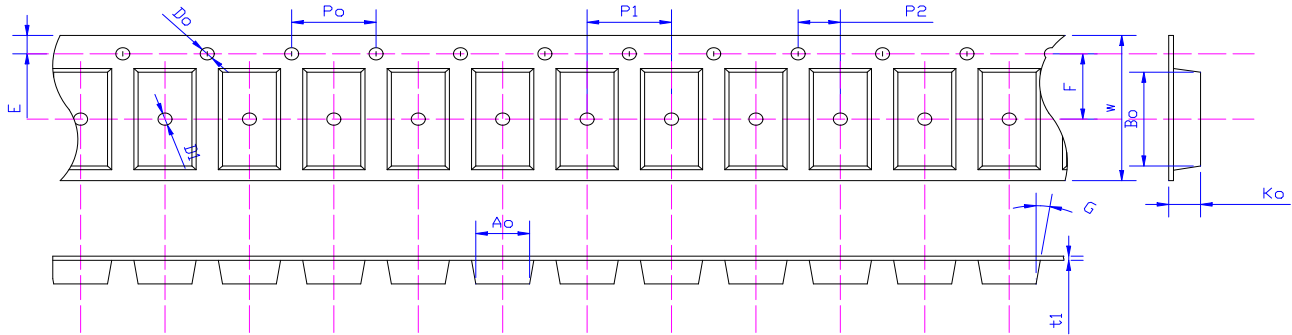
Type number	Marking code
SS32B	SS32
SS34B	SS34
SS35B	SS35
SS36B	SS36
SS38B	SS38
SS310B	SS310
SS315B	SS315
SS320B	SS320



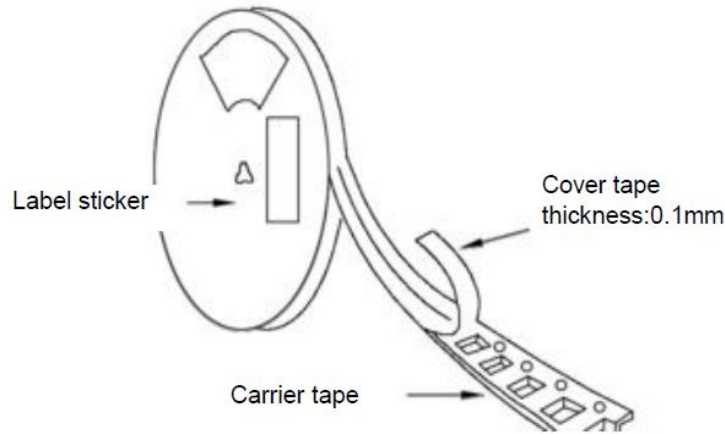
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Package Reel Information



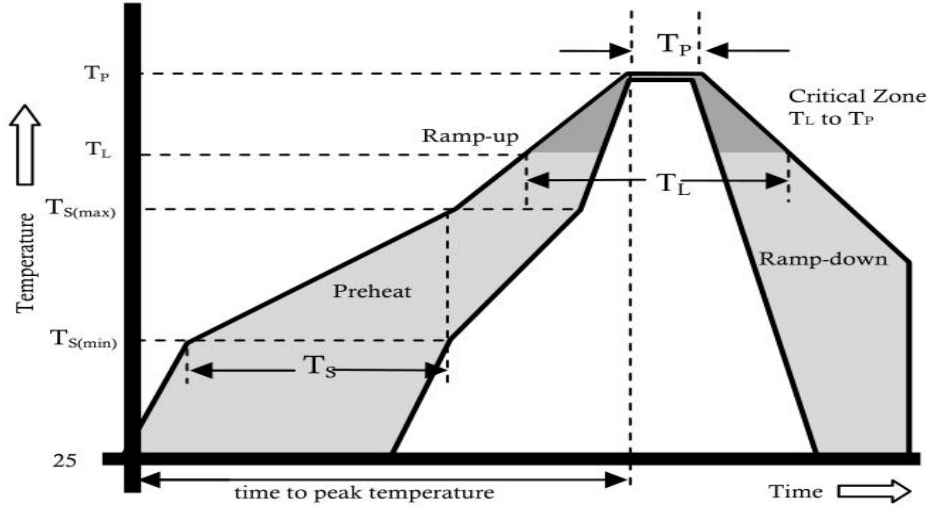
Specifications	Ao	Bo	Ko	Po	W	t1
SMB	3.77±0.10	5.70±0.10	2.67±0.10	4.00±0.1	12.0±0.05	0.23±0.02



DEVICE TYPE	Tape Width	13"Reel			07"Reel			
		Q'TY/REEL(pcs)	BOX/CARTON	Q'TY/CARTON(pcs)	Q'TY/REEL(pcs)	REEL/BOX	BOX/CARTON	Q'TY/CARTON(pcs)
SMB	12mm	3000	8	48000	NA	NA	NA	NA



Reflow Profile



Reflow Condition		Pb-Free Assembly
Pre Heat	Temperature Min.	+150°C
	Temperature Max.	+200°C
	Time(Min to Max)	60-180 secs.
Average ramp up rate(Liquidus Temp(T _L) to peak)		3°C/sec. Max.
T _S (max) to T _L - Ramp-up Rate		3°C/sec. Max.
Reflow	Temperature (T _L)(Liquidus)	+217°C
	Temperature (T _L)	60-150 secs.
Peak Temp (T _P)		+(260±0/-5) °C
Time within 5°C of actual Peak Temp (T _P)		25 secs.
Ramp-down Rate		6°C/sec. Max.
Time 25°C to peak Temp (T _P)		8 min. Max.
Do not exceed		+260°C